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NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE0224D uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

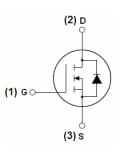
- V_{DS} =200V, I_{D} =24A $R_{DS(ON)}$ < 80mΩ @ V_{GS} =10V (Typ:64mΩ)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



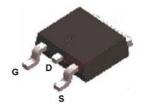
100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-263-2L top view

Package Marking and Ordering Information

	<u> </u>				
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0224D	NCE0224D	TO-263-2L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	200	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	24	Α
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	17	А
Pulsed Drain Current	I _{DM}	100	А
Maximum Power Dissipation	P _D	150	W
Single pulse avalanche energy (Note 5)	E _{AS}	250	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}\mathbb{C}$

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NCE0224D

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{ heta JC}$	1	°C/W	Ì
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Electrical Characteristics (T_C=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	200	220	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =200V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	2	3	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =15A	-	64	80	mΩ
Forward Transconductance	g FS	V _{DS} =50V,I _D =15A	30	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	\/ -25\/\/ -0\/		4200		PF
Output Capacitance	C _{oss}	V_{DS} =25V, V_{GS} =0V, F=1.0MHz		163		PF
Reverse Transfer Capacitance	C _{rss}	F=1.0WHZ		75		PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	10	-	nS
Turn-on Rise Time	t _r	V _{DD} =100V,I _D =15A	-	18	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{GEN} =2.5 Ω	-	22	-	nS
Turn-Off Fall Time	t _f		-	5	-	nS
Total Gate Charge	Qg	\/ -400\/ -454		60		nC
Gate-Source Charge	Q _{gs}	V_{DS} =100V, I_{D} =15A, V_{GS} =10V		19		nC
Gate-Drain Charge	Q _{gd}	V _{GS} -10V		17		nC
Drain-Source Diode Characteristics	Drain-Source Diode Characteristics					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =11A	-	-	1.2	V
Diode Forward Current (Note 2)	Is	-	-	-	24	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 15A	-	90	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	300	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD				y LS+LD)

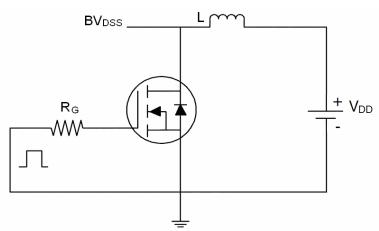
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V_{DD}=100V,V_G=10V,L=0.5mH,Rg=25 Ω

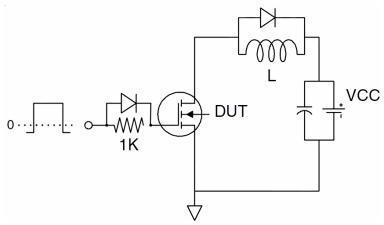


Test circuit

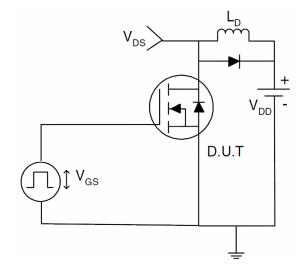
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

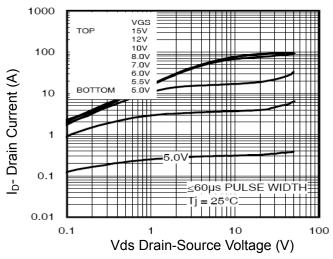


Figure 1 Output Characteristics

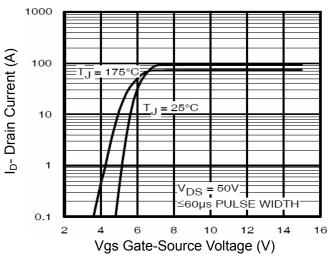


Figure 2 Transfer Characteristics

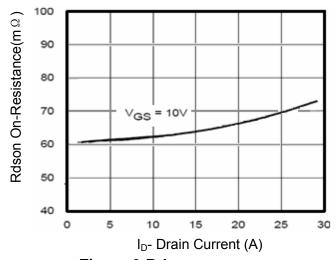


Figure 3 Rdson- Drain Current

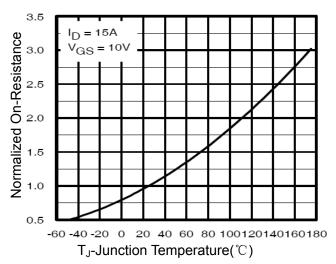


Figure 4 Rdson-JunctionTemperature

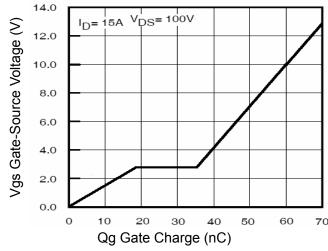


Figure 5 Gate Charge

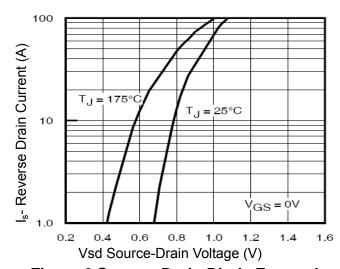


Figure 6 Source- Drain Diode Forward



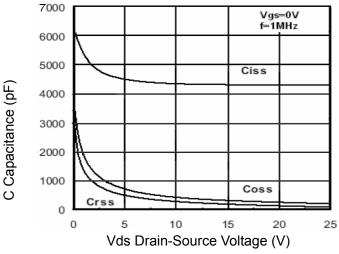


Figure 7 Capacitance vs Vds

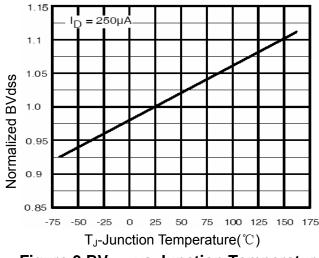


Figure 9 BV_{DSS} vs Junction Temperature

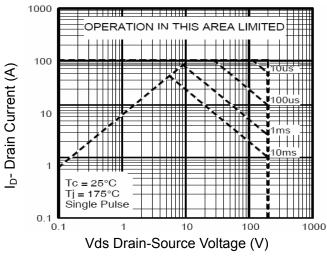
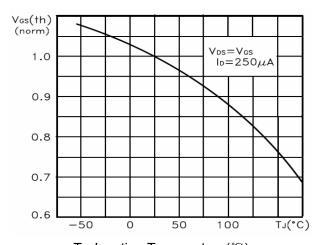


Figure 8 Safe Operation Area



 T_{J} -Junction Temperature(${}^{\circ}\mathbb{C}$)

Figure 10 V_{GS(th)} vs Junction Temperature

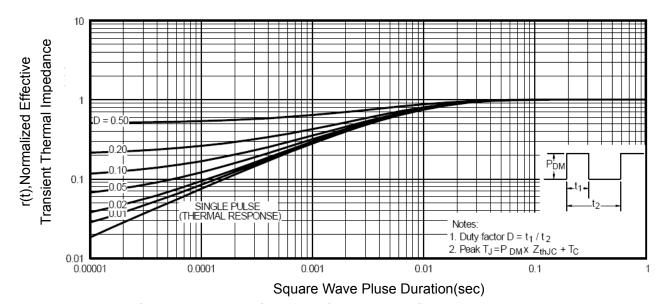


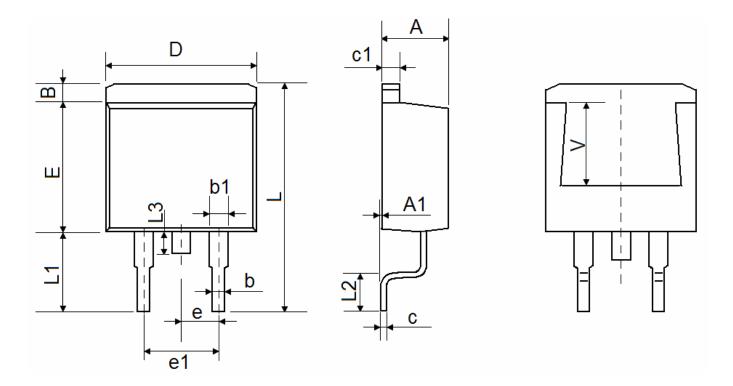
Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-263-2L Package Information



Compleal	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	4.470	4.670	0.176	0.184	
A1	0.000	0.150	0.000	0.006	
В	1.170	1.370	0.046	0.054	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.310	0.530	0.012	0.021	
c1	1.170	1.370	0.046	0.054	
D	10.010	10.310	0.394	0.406	
E	8.500	8.900	0.335	0.350	
е	2.540	TYP.	0.100	TYP.	
e1	4.980	5.180	0.196	0.204	
L	15.050	15.450	0.593	0.608	
L1	5.080	5.480	0.200	0.216	
L2	2.340	2.740	0.092	0.108	
L3	1.300	1.700	0.051	0.067	
V	5.600	REF	0.220 REF		



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